## NSN 5962-01-283-9165

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View Online at https://aerobasegroup.com/nsn/5962-01-283-9165 **Body Length:** 1.290 inches **Body Width:** 0.600 inches **Body Height:** 0.180 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **Features Provided:** High performance and schottky and high speed and high reliability and multichip and low power and 3-state output and monolithic and bipolar and electrostatic sensitive and hermetically sealed and programmable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 14 input **Current Rating Per Characteristic:** 185.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 5.0 volts power source **Capitance Rating Per Characteristic:** 12.00 output picofarads **Time Rating Per Chacteristic:** 55.00 nanoseconds access **Memory Device Type:** Prom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a **Unit Of Measure:** 

**Demilitarization:** 

Yes - demil/mli

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